RoHS

HALOGEN FREE

**GREEN** 



Vishay Semiconductors

# Bidirectional Symmetrical (BiSy) Single Line ESD-Protection Diode in LLP1006-2M





**MARKING** (example only)



Bar = pin 1 marking X = date code Y = type code (see table below)

#### **LINKS TO ADDITIONAL RESOURCES**





#### **FEATURES**

- Ultra compact LLP1006-2M package
- Low package height < 0.4 mm
- 1-line ESD protection
- Working range ± 3.5 V
- Low leakage current < 0.1 μA
- Low load capacitance C<sub>D</sub> = 12.5 pF
- ESD immunity acc. IEC 61000-4-2 ± 18 kV contact discharge
  - ± 20 kV air discharge
- Soldering can be checked by standard vision inspection, no X-ray necessary
- Pin plating NiPdAu (e4) no whisker growth
- PATENT(S): www.vishay.com/patents
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

ORDERING INFORMATION					
DEVICE NAME ORDERING CODE		TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY		
VCUT03B1-DD1	VCUT03B1-DD1-G-08	8000	8000		

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VCUT03B1-DD1	LLP1006-2M	N	0.72 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C

ABSOLUTE MAXIMUM RATINGS VCUT03B1-DD1						
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT		
Peak pulse current	Acc. IEC 61000-4-5; $t_p = 8/20 \mu s$ ; single shot	I <sub>PPM</sub>	3.5	А		
Peak pulse power	Pin 1 to pin 2 Acc. IEC 61000-4-5; $t_p = 8/20 \mu s$ ; single shot	P <sub>PP</sub>	40	W		
ESD immunity	Contact discharge acc. IEC61000-4-2; 10 pulses	V	± 18	kV		
	Air discharge acc. IEC61000-4-2; 10 pulses	$V_{ESD}$	± 20			
Operating temperature	Junction temperature	TJ	-40 to +125	°C		
Storage temperature		T <sub>STG</sub>	-55 to +150	°C		

PATENT(S): www.vishay.com/patents

This Vishay product is protected by one or more United States and international patents.

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#### **CUT THE SPIKES WITH VCUT03B1-DD1**

The VCUT03B1-DD1 is a bidirectional and symmetrical (BiSy) ESD protection device which clamps positive and negative overvoltage transients to ground. Connected between the signal or data line and the ground the VCUT03B1-DD1 offers a high isolation (low leakage current, low capacitance) within the specified working range. Due to the short leads and small package size of the tiny LLP1006-2M package the line inductance is very low, so that fast transients like an ESD strike can be clamped with minimal over- or undershoots.

<b>ELECTRICAL CHARACTERISTICS VCUT03B1-DD1</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines	
Reverse stand-off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	3.5	V	
Reverse voltage	At I <sub>R</sub> = 0.1 μA	$V_{R}$	3.5	-	-	V	
Reverse current	At V = 3.5 V	I <sub>R</sub>	-		0.1	μΑ	
Reverse breakdown voltage	At I =1 mA	$V_{BR}$	5.8	6.7	7.5	V	
Reverse clamping voltage	At I <sub>PP</sub> = 1 A	V <sub>C</sub>	-	7.8	9	V	
	At I <sub>PP</sub> = I <sub>PPM</sub> = 3.5 A	V <sub>C</sub>	-	9.5	11.5	V	
Capacitance	At V = 0 V; f = 1 MHz	C <sub>D</sub>	-	12.5	15	pF	
	At V = 2.5 V; f = 1 MHz	C <sub>D</sub>	-	11.5	-	pF	

## TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

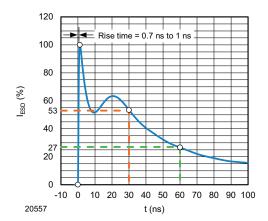


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330  $\Omega$ /150 pF)

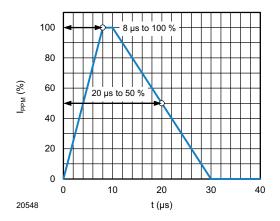


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5



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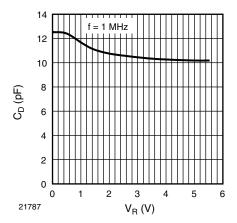


Fig. 3 - Typical Capacitance  $C_D$  vs. Reverse Voltage  $V_R$ 

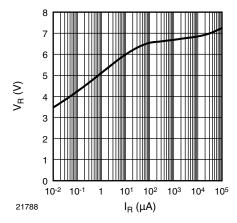


Fig. 4 - Typical Forward Current I<sub>F</sub> vs. Forward Voltage V<sub>F</sub>

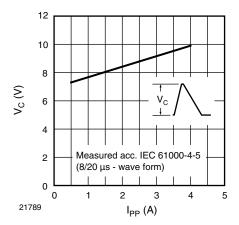


Fig. 5 - Typical Reverse Voltage  $V_{\mbox{\scriptsize R}}$  vs. Reverse Current  $I_{\mbox{\scriptsize R}}$ 

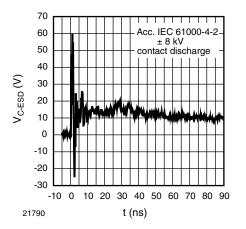


Fig. 6 - Typical Peak Clamping Voltage  $V_{\rm C}$  vs. Peak Pulse Current  $I_{\rm PP}$ 

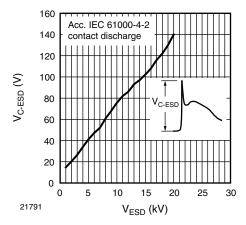
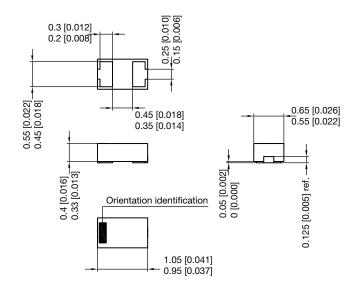


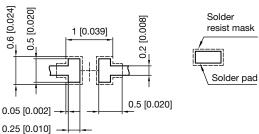
Fig. 7 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

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### PACKAGE DIMENSIONS in millimeters (inches): LLP1006-2M



#### Foot print recommendation:

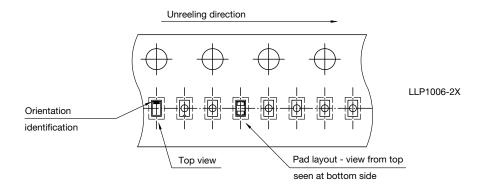


Pad Design Patented: (P)US 9.018.537 B2)

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